

Docket: P910270

Hoang, Quoc Dinh

## TRADES PATENT AND TRADEMARK OFFICE

Applicant:

Chen et al.

Serial No.:

10/661,089

Filed:

September 10, 2003

For:

METHOD FOR MITIGATING

CHEMICAL VAPOR DEPOSITION PHOSPHORUS DOPING OXIDE SURFACE INDUCED DEFECTS

I hereby certify that this correspondence is being deposited with the United States Postal Service, First Class mail, postage prepaid, in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria,

2818

VA 22313-1450 on April 26, 2005. STOUT, UXA, BUYAN & MULLINS, LLP

Examiner:

Group Art Unit:

Kenton R. Mullins, Reg. No. 36,331

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## **TRANSMITTAL**

Sir:

Submitted herewith are

~ Amendment (7 pages including this Transmittal); and

~ The Commissioner is hereby authorized to charge any needed fees to deposit account 50-1600.

Respectfully submitted,

Kenton R. Mullins Attorney for Applicants Registration No. 36,331

April 26, 2005 STOUT, UXA, BUYAN & MULLINS, LLP 4 Venture, Suite 300 Irvine, CA 92618

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## <u>AMENDMENT</u>

Dear Sir:

In response to the Office Action mailed January 26, 2005, Applicants respectfully request that the following amendments be entered in the above-identified patent application:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.